



# isc Silicon NPN Power Transistor

#### **DESCRIPTION**

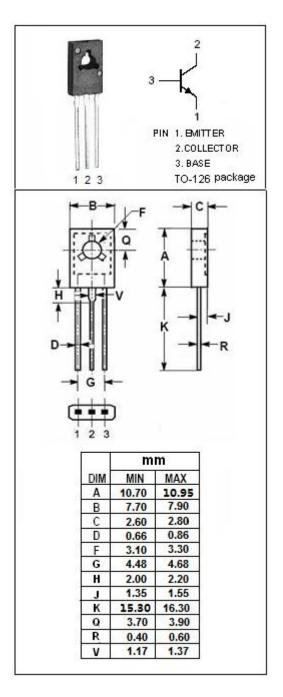
- High Collector Current Ic= 1A
- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= 50V(Min)
- · Good Linearity of hFE
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### **APPLICATIONS**

• Designed for low frequency power amplifier applications.

# ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	50	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	50	V	
V <sub>EBO</sub>	Emitter-Base Voltage	V		
Ic	Collector Current-Continuous	1	Α	
P <sub>C</sub>	Collector Power Dissipation @ T <sub>C</sub> =25°C	8	W	
	Collector Power Dissipation @ T <sub>a</sub> =25℃	0.75	VV	
TJ	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature Range	-55~150	${\mathbb C}$	





# isc Silicon NPN Power Transistor

2SC1212

#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 1mA ; I <sub>E</sub> = 0	50			V
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA ; R <sub>BE</sub> = ∞	50			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Vltage	I <sub>E</sub> = 1mA ; I <sub>C</sub> = 0	4			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 1A; I <sub>B</sub> = 0.1A			1.5	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 50mA ; V <sub>CE</sub> = 4V			1.0	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 50V; I <sub>E</sub> = 0			5	μА
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 50mA; V <sub>CE</sub> = 4V	60		200	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 4V	20			
f⊤	Current-Gain—Bandwidth Product	I <sub>C</sub> = 30mA ; V <sub>CE</sub> = 4V		160		MHz

## ♦ h<sub>FE-1</sub> Classifications

В	С
60-120	100-200

## NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications. ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

isc website: www.iscsemi.cn